































流磁 60	Comment COS 100MHz	型号 PB2012-601/1A5	Description 600C @ 100MHz x25%	Daxignator B1	Quantity 1	万 家 新华富	COMMEN	558 0005
2:14s	tuF	QJB/K+-CT41G- 0803-XTR-25V-10S- K-N	1sF,二英,±10%,25V,-65-125°C	C1A, C1B, C1C, C1D, C1E, C2A, C2B, C2C, C2D, C2E, C27A, C27B, C36, C37, C38, C39, C40, C41, C42, C43, C44, C46, C51, C52, C53, C54, C55, C56, C57, C58, C56, C57,	32	ΧE	,	0603
能介地	100nF	DJBIK+-CT41G- beco-xtrk-50V-104- K-N	1004F	C55. C55. C60. C53. C55. C55. C53. C55. C55. C53. C55. C55. C55. C56.	74	炖	r	0603
的地	100pF	QJB/K+-CC41- 0603-CG-50V-101- J-N	100pF,—美.x5%,50V,-55-125℃	CSD, CSE, CBA, CBB, CBC, CBD, CBE, C33,	12	地	,	0603
的他	10uF	QJB/K+-CT41G- 0805-X7R-10V-106- M-N	10uF,二美,420%,10V,-55-125°C	C76 C10A, C10B, C11A, C11B, C13A, C13B, C14A, C14B, C19A, C19B	10	X矩	,	0805
かき	22uF	QJB/K-CT41G- 0805-XSR-10V-226- M-N QJB/K+-CC41-	22uF,_g,u20%,10V,-55-125°C	C20A, C20B C23A, C23B, C24A, C24B	2	烘	·	0805
東介电 日 東介电	100pF 12pF	0402-CG-50V-101- J-N DJB/K+-CC41- 0402-CG-50V-120-	100pF,一美,45%,50V,-55-125°C 12pF,一美,45%,50V,-55-125°C	C25A, C25B, C26A, C25B, C26A, C26B,	4	XE		0402
加加	toF	J-N QJB/K+-CT41G- 0603-X7R-50V-102-	1eF,二美±10%,50V,55-125°C	C29A, C29B	2	大矩 大矩		0603
原介电	330vF	K-N QJB/K+-CT41G- 0603-X7R-50V-334-	330eF 8-410%-50V-55-125°C	C46, C61	2	XE		0603
i 記分地	470pF	K-N DJB/K+-CC41- 0603-CG-50V-471- LN	470pF,	C47, C62	2	XE	,	0603
· 片式 B容器	270nF	TCC0603X7R274K 500CT, QJBM+- CT41G-0603-X7R- 50V-274-K-N	議費 ±10% 容值 270eF 設定地理 SSV 血面系数 (介质材料) XTR, 270eF,二美, ±10%,10%,455-125m	C48, C49, C50, C63, C64, C65	6	CCTC(三 球〉大矩	C376826,/	0603
京介电	10nF	50V-274-K-N DJB/K+-CT41G- 0603-X7R-50V-103- K-N	#10%,16V,-65-125°C 10eF,	C68A, C68B, C68C, C68D, C68E, C72A, C72B, C72C, C72D,	10	X地	,	0603
-	0340A-13-F	B342A-13-F	直流反向配性 (Vr) 40V 平均整流电流 (Io) 3A 正向狂舞 (VI) 550mV @ 3A	C72E D1A, D1B	2	DIODES(#	C85098	SMA
iż	IPEX 530470510	734120110 530470510	正均打算 (VI) SSOmV @ 3A RF同報连接器 (天候度) MXI.25 直延 機能 SP 計度	J2A, J08 J3A J08	2 2	MOLEX MOLEX	C434806 C471412	SMD 1.25mm Sc
PRE	2.2uH 6.8uH	NR201610-2R2M PI2012G6R8M	市務值 2.2kH	L1A, L1B L2A, L2B	2	振华富		NR2016
(空管) (2%	6.8UH	DMG6968UDM-7	高度 10% 高度 10% 直接高限电流 (d) (25°C bj) 6.5A 指移取過售电阻 200mV @ 25°DA 無移取過售电阻 20mD @ 6.5A.4.5V 最大力率耗数 (Tau25°C) 850mW 後世 20%回應共業	QIA, QIB	2	新学宴 DICODES(美 台)	C151635	S0723-6
PRINTER	108	"LMSTRMK1608-K- B-100-F- LMS0S0101001- 2017	を登りたりを共動 10R,41%,50V,0.1W,4100ppm/c	R1A, R1B, R1C, R1D, R1E, R2A, R2B, R2C, R2D, R2E, R2A, R3B, R5C, R5D, R5E, R13A, R13B, R29, R35, R42, R4B, R54C, R54B, R54B, R54C, R54B, R54B, R54C, R54B, R54B, R54B, R54B, R54B, R54B, R54B, R54B, R54B, R54B, R54B, R54B, R54B,	33	718	,	0603
Ertelle istor	16	"LMSTRMR(1608-K- B-1001-F- LMS0S0101001- 2017, RS- 03K1001FT	K.a1%,50V.0.1W.a100ppm/C, 施度 a 1% 速度系数 a100ppm/C 設度 150 UD\$ 0.1W	H.S. 1820, FEB. IND. PIEL REA, PIER, NO. REC. REO. REC. REO. REC. REO. REC. REO. REC. RESO. RESC. REC. REC. REC. REC. REC. REC. REC. RE	40	718, FH(K) \$0	i, C115325	0603
erelia.	1010	"LMSTRMK1608-K- B-1002-F- LMS050101001- 2017	10K,a1%,50V,0.1W,a100ppm/°C	R4A, R4B, R4C, R4D, R4E, R7A, R7B, R7C, R7D, R7E, R1BA, R18B, R22, R23, R24, R25, R34, R30, R40, R47, R40, R512, R57D, R57E, R61A, R61B, R61C, R61D, R61E, R62, R66, R67	35	718	,	10603
ena	470R	"LMS"RMK1606-K- B-4700-F- LMS050101001- 2017 "LMS"RMK1606-K-	470R, s1%, 50V, 0.1W, s100ppm/°C	RSA, RSS	2	718	,	0603
Ertelli	211	B-2001-F- LMIS0S0101001-	2K,a1%,50V,0.1W,a100ppm/rg	RSA, RSS	2	718	,	0603
ena	10M	PLMSTRMK1608-K- B-1005-F- LMS050101001- 2017 TLMSTRMK1608-K-	10M,a1%,50V,0.1W,a100ppm/rg	R10A, R10B, R11A, R11B	4	718	,	0603
enta.	100K	B-1003-F- LMS050101001- 2017, "LMS" RMK1608-Y-B- 1003-B-	100K,a1%,50V,0.1W,a100ppm/°C, 100K,a0.1%,50V,0.1W,a10ppm/°C	R12A, R12B, R14A, R14B, R17A, R17B, R3B, R51		718	,	0603
ene	330R	2017 "LMSTRMK1608-K- B-3300-F- LMS050101001-	330R, s1%, 50V, 0.1W, s100ppm/°C	R15, R16	2	718	,	0603
Erthill.	GR.	2017 'LMS' RMZ1608-B- T-30-Q/RV20573- 2010	<00m0	R19A, R19B, R20A, R20B	4	718	r	0603
ente	47R	LMS/RMK1608-K- B-470-F- LMS050101001-	47R,a1%,50V,0.1W,a100ppm/°C	R21, R27, R30, R31, R32, R33, R43, R44, R45, R46	10	718	,	0603
18	10K	EMS050101001- 2017 RNKS084-M-E- 1002-F-GJB7690- 2012 PTS1209M181K00	10K ,s1%,40V,0.1W,s300ppm/°C	R45, R46 R36, R52	2	718		0603
pr Pr	S1200M1B1K 00P100 EF332SAIDBZ R	PTS1206M1B1K00 P100 PEF332SAIDGZR	PT1000 部分地区 (債小価値定) 2.5V 能分地区 (債小価値定) 2.5V 能分地区 (成大値) - (成大値) - (成大値) - (成大値) - (の表して 5.5A 能分地区 (版文 1.5E) - (の表して 1.5E) - (のまして 1.5E)	R37, R50 U1A, U1B, U1C, U1D, U1E	5	FH(R(S))	C320418	1206 50723-3
	T.V333IDCK	TLV333IDCK	参考達定型 系列 物達的技 1.8V - 5.5V, x0.5V - 2.75V 地址等的的 (GBP) 35500 tr 技術車 (GBP) 0.16 Vius 工作温度 -40°C - 125°C	U2A, U2B, U2C, U2D, U2E, U3A, U3B, U3C, U3D, U3E, USA, USB, U7, U8	14	танка	C181502	SC-70-S
	8261AAJMD- G2JT2S	5-8261AAJMD- G2JT2S	単节电池保护芯片 位別4.325V 位別4.55V 位別550mV	UIA, UIB	2	ABLIC(党會 液和)	C125801	S0723-6
H TP	562740055R 1310F128RG ZR	TPS62740DSSR CC1310F128RGZR	bcbc	USA, USB	2	TOWNSHEE TOWNSHEE	C128606 C84353	0550012A VQFN-48
n 060	50BM14E0016	0850BM14E0016	RF-MCU RF-MCU -80°C to +85°C Pmax 2W 803 - 90000tc	UIGA, UIGB	2	Johanson Technology		6P0603
09	OOLP15BOOKS	0900LP1580063	3Fo Attenuation (2589-2784MHz) 50dB 2Fo Attenuation (1726-1856MHz) 50dB	UI1A, UI1B	2	Johanson Technology		8P0805 SOT23-
	35131E085PA	TPL5010DDCR ADS131E085PAG	新门的	U12A, U12B U13, U16	2	Панка панка	C473912 C1520670	SOT23- Thin-6 TQFP-64
ey Ri	G EF3312AIDBZ R	REF3312AIDBZR	8399	U14, U17	2	Панка	C183104	SOT23-3
T	DS18820 AD6278RZ	DS18820 AD6278RZ	國業性等語2.5-5.5V 超益界変数 (GEP) (SSH-14,3-3四) 放大器総数 (SSH-14-Rail 総元発型 Pasi+10-Rail 位数発型 Instrumentation 任理事 (GR) 0.05 VMs 1/年間を 40°C -45°C	U15, U18 U19A, U19B, U19C, U19D, U19E, U2DA, U20B, U2DC, U2DD, U2DE	10	TORNOS	C473912 C19137	TO-92 SOIC- 8_150mil
校館	BATS4C	BATS4C,215	共開發。 Fi-0.24,VRRM-30V,VF-0.24V等0.1m A,IR-22A等25V,tri-Sns,SOT23-3,-55℃ 150℃	VD1, VD2	2	Nesperial(g)	C37704	SOT-23-3
	24MHZ	JA144-24-C10-83- D10-E	等性自転車的 (ESR) <500	X1A, X1B	2	RE EPSONIE		SMD-3225 SMD- 3215_2P
			24MHZ JA144-24-C10-83- D10-6	### ### ### ### ### ### ### ### ### ##		BATSAC BATSAC 215	BATSAC BATSAC 25 FEATURE STATE	BATSIC DATES CONTROL OF THE PROPERTY OF THE PR